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151545 PTO

	Subclass	CLASS

**PATENT NUMBER**

**U.S. UTILITY Patent Application**

**O.I.P.E.**  
M A C H 19 1971  
SCANNED O.A. GUL

**PATENT DATE**

APPLICATION NO. 09/845845	CONT/PRIOR	CLASS 313	SUBCLASS 311	ART UNIT 2879	EXAMINER PHINNEY
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Nobuyoshi Kastida  
Huei-Pei Kuo

Silicon emitter with low resistivity heavily doped contact layer

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PTO-2040  
12/99

**ISSUING CLASSIFICATION**

<input type="checkbox"/> <b>TERMINAL DISCLAIMER</b>	<b>DRAWINGS</b>			<b>CLAIMS ALLOWED</b>	
<input type="checkbox"/> The term of this patent subsequent to _____ (date) has been disclaimed.	<b>Sheets Drwg.</b> _____	<b>Figs. Drwg.</b> _____	<b>Print. Fig.</b> _____	<b>Total Claims</b> _____	<b>Prim. Claim for O.G.</b> _____
<input type="checkbox"/> The term of this patent shall not extend beyond the expiration date of U.S. Patent No. _____ _____ _____	<b>(Assistant Examiner)</b> _____ _____	<b>(Date)</b> _____ _____	<b>NOTICE OF ALLOWANCE MAILED</b> _____ _____		
<input type="checkbox"/> The terminal _____ months of this patent have been disclaimed.	<b>(Primary Examiner)</b> _____ _____	<b>(Date)</b> _____ _____	<b>ISSUE FEE</b> _____ _____		
<input checked="" type="checkbox"/> The terminal _____ months of this patent have been disclaimed.	<b>(Large Instruments Examiner)</b> _____ _____	<b>(Date)</b> _____ _____	<b>ISSUE PAYMENT NUMBER</b> _____ _____		

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